

Drafts

ISNR:

Pending

Active

L1: (8) interfacial adj transition adj

L2: (2935) optoelectronic adj device

L3: (8) 2 and interfacial adj layer

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US PATENT OFFICE

Default: 10/10/10

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2 and interfacial adj layer

		Document ID	Issue Date	Pages	Title	Current OR	Current KR	Retrieval	
1	US	20030020104	20030130	53	Increased efficiency semiconductor devices	257/295	257/192;		Talin, et al.
2	US	20020085784	20020704	18	Integrated lightguide-optoelectron	385/14	257/197;		Reimer
3	US	20020074553	20020620	23	One-chip micro-integrated optoelect	257/77			Starik, al.
4	US	6608360	20030819	19	One-chip micro-integrated optoelect	257/481	257/449;		Starik, al.
5	US	5540786	19960730	7	Light emitting material	148/33.4	257/453;		Xu, Gu
6	A	5351255	19940927	51	Inverted integrated heterostructure of group	372/45	148/33.5;		Schetz
7	A	5272355	19931221	10	Optoelectronic switching and display d	257/3	257/12;		Namava
8	A	5258327	19931102	5	MBE growth method for high level devices and	117/106	257/103;		et al.
							257/55;		Pao, Y.
							257/E21.13		
							1;		

CAST - [Designs.1]

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☐ Drafts
☐ ISNR:
☒ Pending
☒ Active
☒ L1: (1096) 372/99.ccls.!
☒ L3: (1) 2 and interfacial
☒ L2: (62) 1 and vcsel
☒ L4: (1179) 372/96.ccls.!
☒ L5: (565) 4 and mirror
☐ Failed
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☐ UDC
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USPAT:US-PCRU:EPF,JPO:DERWENT:EM:TOB

Default operator: OR

☒ Highlight all hit terms in body

4 and mirror

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	U	Document ID	Issue Dat	Pages	Title	Current OR	Current XR	Retrieval
1	<input type="checkbox"/>	US 20030189963	20031009	32	Low threshold microcavity light emitt	372/96		Deppe et al
2	<input type="checkbox"/>	US 20030185267	20031002	18	VCSEL with antiguide	372/96		Hwang al.
3	<input type="checkbox"/>	US 20030185266	20031002	38	current confinement lav	372/96		Henri Reid
4	<input type="checkbox"/>	US 20030185265	20031002	40	Folded cavity solid-state laser	372/96		Henri Reid
5	<input type="checkbox"/>	US 20030185261	20031002	7	Super-luminescent folded cavity light emi	372/43	372/70; 372/96	Knopp al.
6	<input type="checkbox"/>	US 20030179803	20030925	10	Cavity mirror for optically-pumped vertic	372/96		Sagaw
7	<input type="checkbox"/>	US 20030179802	20030925	9	Vertical cavity surface emitting laser and lase	372/96	372/50	Albre
8	<input type="checkbox"/>	US 20030179801	20030925	10	Surface-emitting laser having lateral current	372/96		Takeu et al
9	<input type="checkbox"/>	US 20030179800	20030925	8	Asymmetric InGaAsN vertical cavity surface	372/96		Uebbi
10	<input type="checkbox"/>	US 20030174750	20030918	21	WAFER BONDED VERTICAL CAVITY SURFACE EMITTING	372/96		Otsub
11	<input type="checkbox"/>	US 20030169797	20030911	14	Surface-emitting laser with a low threshold va	372/45	372/96	
12	<input type="checkbox"/>	US 20030169795	20030911	18	MONOLITHICALLY INTEGRATED MODE-LOCKED	372/96		Aldaz et al
13	<input type="checkbox"/>	US 20030169787	20030911	33	Surface emitting semiconductor laser and	372/46	372/96	Otoma al.
14	<input type="checkbox"/>	US 20030169786	20030911	11	Photonics-crystal distributed-feedback an	372/20	372/102; 372/32; 372/45;	Vurga et al
15	<input type="checkbox"/>	US 20030165171	20030904	16	Micro-electromechanical lv tunable vertical cav	372/20	372/96;	Kapon al.
16	<input type="checkbox"/>	US 20030161368	20030828	41	Temperature compensated lasers	372/46	372/96	Jewel
17	<input type="checkbox"/>	US 20030156617	20030821	8	Organic vertical cavity lasing devices having o	372/39	372/70; 372/96	Kahen al.
18	<input type="checkbox"/>	US 20030156616	20030821	9	Fiber-coupled tunable single-mode long-wavele	372/96		Baney et al
19	<input type="checkbox"/>	US 20030156616	20030821	9	Long wavelength VCSEL bottom mirror	372/96		Kwon,